

Low Offset drift, ±0.5g Dual Axis Accelerometer with Ratiometric Output

MXR2999E

FEATURES

Better than 1 mg resolution
Dual axis accelerometer fabricated on a monolithic CMOS IC
RoHS compliant
On-chip mixed mode signal processing
No moving parts
50,000 g shock survival rating
±0.4mg/°C offset drift over temperature
3V to 5.25V single supply continuous operation
Small (5mm x 5mm x 2mm) surface mount package
Continuous self test
Custom programmable specifications
Independently axis programmable axes (special order)

APPLICATIONS

Automotive – Vehicle Security/Active Suspension/ABS
Headlight Angle Control/Tilt Sensing
Security – Gas Line/Elevator/Fatigue Sensing
Office Equipment – Computer Peripherals/PDA/Cell
Phones/Digital Projectors
Gaming – Joystick/RF Interface/Menu Selection/Tilt Sensing
White Goods – Spin/Vibration Control

Sck Internal Temperature Tout (optional) Voltage CLK Reference Continous Heate Control I ow Pass X axis $\mathbf{A}_{\mathsf{OUTX}}$ Filter W Factory Adjust Offset & Gain 11 ĺΜ Low Pass Filter 2-AXIS SENSOR Gnd V_{DA}

MXR2999E FUNCTIONAL BLOCK DIAGRAM

GENERAL DESCRIPTION

The MXR2999E is a low noise and low cost, dual axis accelerometer fabricated on a standard, submicron CMOS process. It is a complete sensing system with on-chip mixed mode signal processing. The MXR2999E measures acceleration with a full-scale range of $\pm 0.5~g$ and a sensitivity of 1000 mV/g @5Vat 25°C. It can measure both dynamic acceleration (e.g., vibration) and static acceleration (e.g., gravity). The MXR2999E design is based on heat convection and requires no solid proof mass. This eliminates stiction and particle problems associated with competitive devices and provides shock survival up to 50,000~g, leading to significantly lower failure rates and lower loss due to handling during assembly.

The MXR2999E provides two ratiometric analog outputs. The typical noise floor is $0.2 \text{ mg}/\sqrt{Hz}$ allowing signals below 1mg to be resolved at 1 Hz bandwidth. The 3dB rolloff of the device occurs at 17 Hz. The offset drift over temperature is $\pm 0.4\text{mg}/^{\circ}\text{C}$. The MXR2999E is available in a small surface mount package (5mm x 5mm x 2mm). It is hermetically sealed and is operational over a -40°C to +105°C temperature range. It also contains an on-chip temperature sensor and a bandgap voltage reference.

Due to the standard CMOS structure of the MXR2999E, additional circuitry can easily be incorporated into custom versions for high volume applications. Contact the factory for more information.

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MXR2999E SPECIFICATIONS (Measurements @ 25°C, Acceleration = 0 g unless otherwise noted; V_{DD} , V_{DA} = 5.0V unless otherwise specified)

			MXR2999E			
Parameter	Conditions	Min	Тур	Max	Units	
SENSOR INPUT	Each Axis					
Measurement Range ¹		± 0.5			g	
Nonlinearity	Best fit straight line		0.5	1.0	% of FS	
Alignment Error ²			± 1.0		degrees	
Transverse Sensitivity ³			±2.0		%	
SENSITIVITY	Each Axis					
Sensitivity, Analog Outputs at pins						
A _{OUTX} and A _{OUTY}		950	1000	1050	mV/g	
Change over Temperature (uncompensated) ⁴	Δ from 25°C, at –40°C			+120	%	
	Δ from 25°C, at +105°C	-55			%	
Change over Temperature (compensated) ⁴	Δ from 25°C, -40 °C to $+105$ °C		< 3.0		%	
ZERO g BIAS LEVEL	Each Axis					
0 g Offset		-0.1	0.00	+0.1	g	
0 g Voltage		2.40	2.50	2.60	V	
0 g Offset over Temperature	Δ from 25°C		±0.4		mg/°C	
	Δ from 25°C, based on 1000mV/g		±0.4		mV/°C	
NOISE PERFORMANCE						
Noise Density, rms	Without frequency compensation		0.2	0.4	mg/\sqrt{Hz}	
FREQUENCY RESPONSE						
3dB Bandwidth - uncompensated		15	17	19	Hz	
TEMPERATURE OUTPUT						
T _{out} Voltage		1.15	1.25	1.35	V	
Sensitivity		4.6	5.0	5.4	mV/°K	
VOLTAGE REFERENCE OUTPUT						
V _{Ref} output	@3.0V-5.25V supply	2.4	2.5	2.65	V	
Change over Temperature			0.1		mV/°C	
Current Drive Capability	Source			100	μΑ	
SELF TEST						
Continuous Voltage at A _{OUTX} , A _{OUTY} under	@5.0V Supply, output rails to					
Failure	supply voltage		5.0		V	
Continuous Voltage at A _{OUTX} , A _{OUTY} under	@3.0V Supply, output rails to					
Failure	supply voltage		3.0		V	
A _{OUTX} and A _{OUTY} OUTPUTS						
Normal Output Range	@5.0V Supply	1.0		4.0	V	
Current	Source or sink, @ 3.0V-5.25V supply			100	μΑ	
Turn-On Time	@5.0V Supply		160		mS	
	@3.0V Supply		300		mS	
POWER SUPPLY						
Operating Voltage Range		3.0		5.25	V	
Supply Current	@ 5.0V	2.7	3.8	4.1	mA	
Supply Current	@ 3.0V	3.2	4.0	4.8	mA	
TEMPERATURE RANGE						
Operating Range		-40		+105	°C	

NOTES

¹ Guaranteed by measurement of initial offset and sensitivity.

² Alignment error is specified as the angle between the true and indicated axis of sensitivity.

 $^{^3\,}$ Transverse sensitivity is the algebraic sum of the alignment and the inherent sensitivity errors.

⁴ The sensitivity change over temperature for thermal accelerometers is based on variations in heat transfer that are governed by the laws of physics and it is highly consistent from device to device. Please refer to the section in this data sheet titled "Compensation for the Change of Sensitivity over Temperature" for more information.

ABSOLUTE MAXIMUM RATINGS*

Supply Voltage (V_{DD}, V_{DA})	0.5 to +7.0V
Storage Temperature	65°C to +150°C
Acceleration	50,000 g

*Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; the functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Package Characteristics

Package	$\theta_{ m JA}$	$ heta_{ m JC}$	Device Weight
LCC-8	110°C/W	22°C/W	< 1 gram

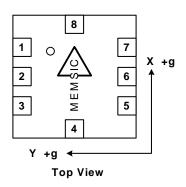
Ordering Guide

Model	Package Style	
MXR2999EL	LCC8, RoHS compliant	
MXR2999EF	LCC8, Pb-free, RoHS compliant	

^{*}LCC parts are shipped in tape and reel packaging.

Caution

ESD (electrostatic discharge) sensitive device.



Pin Description: LCC-8 Package

Pin	Name	Description	I/O
1	T _{OUT}	Temperature (Analog Voltage)	О
2	A _{OUTY}	Y-Axis Acceleration Signal	О
3	Gnd	Ground	I
4	V_{DA}	Analog Supply Voltage	I
5	A _{OUTX}	X-Axis Acceleration Signal	О
6	V _{ref}	2.5V Reference Output	О
7	Sck	Optional External Clock	I
8	V_{DD}	Digital Supply Voltage	I



Note: The MEMSIC logo's arrow indicates the +X sensing direction of the device. The +Y sensing direction is rotated 90° away from the +X direction following the right-hand rule. Small circle indicates pin one (1).

THEORY OF OPERATION

The MEMSIC device is a complete dual-axis acceleration measurement system fabricated on a monolithic CMOS IC process. The device operation is based on heat transfer by natural convection and operates like other accelerometers having a proof mass except it is a gas in the MEMSIC sensor.

A single heat source, centered in the silicon chip is suspended across a cavity. Equally spaced aluminum/polysilicon thermopiles (groups of thermocouples) are located equidistantly on all four sides of the heat source (dual axis). Under zero acceleration, a temperature gradient is symmetrical about the heat source, so that the temperature is the same at all four thermopiles, causing them to output the same voltage.

Acceleration in any direction will disturb the temperature profile, due to free convection heat transfer, causing it to be asymmetrical. The temperature, and hence voltage output of the four thermopiles will then be different. The differential voltage at the thermopile outputs is directly proportional to the acceleration. There are two identical acceleration signal paths on the accelerometer, one to measure acceleration in the x-axis and one to measure acceleration in the y-axis. Please visit the MEMSIC website at www.memsic.com for a picture/graphic description of the free convection heat transfer principle.

PIN DESCRIPTIONS

 $V_{DD}\,-$ This is the supply input for the digital circuits and the sensor heater in the accelerometer. The DC voltage should be between 3.0 and 5.25 volts. Refer to the section on PCB layout and fabrication suggestions for guidance on external parts and connections recommended.

 V_{DA} – This is the power supply input for the analog amplifiers in the accelerometer. Refer to the section on PCB layout and fabrication suggestions for guidance on external parts and connections recommended.

Gnd – This is the ground pin for the accelerometer.

 A_{OUTX} – This pin is the output of the x-axis acceleration sensor. The user should ensure the load impedance is sufficiently high as to not source/sink >100 μA . While the sensitivity of this axis has been programmed at the factory to be the same as the sensitivity for the y-axis, the accelerometer can be programmed for non-equal sensitivities on the x- and y-axes. Contact the factory for additional information.

 A_{OUTY} – This pin is the output of the y-axis acceleration sensor. The user should ensure the load impedance is sufficiently high as to not source/sink >100 μA . While the sensitivity of this axis has been programmed at the factory to be the same as the sensitivity for the x-axis, the

accelerometer can be programmed for non-equal sensitivities on the x- and y-axes. Contact the factory for additional information.

 T_{OUT} – This pin is the buffered output of the temperature sensor. The analog voltage at T_{OUT} is an indication of the die temperature. This voltage is useful as a differential measurement of temperature from ambient and not as an absolute measurement of temperature. After correlating the voltage at T_{OUT} to 25°C ambient, the change in this voltage due to changes in the ambient temperature can be used to compensate for the change over temperature of the accelerometer offset and sensitivity. Please refer to the section on Compensation for the Change in Sensitivity Over Temperature for more information.

Sck – The standard product is delivered with an internal clock option (800kHz). This pin should be grounded when operating with the internal clock. An external clock option can be special ordered from the factory allowing the user to input a clock signal between 400kHz and 1.6MHz.

 V_{ref} – This pin is the output of a reference voltage. It is set at 2.50V typical and has 100 μA of drive capability.

COMPENSATION FOR THE CHANGE IN SENSITIVITY OVER TEMPERATURE

All thermal accelerometers display the same sensitivity change with temperature. The sensitivity change depends on variations in heat transfer that are governed by the laws of physics. Manufacturing variations do not influence the sensitivity change, so there are no unit to unit differences in sensitivity change. The sensitivity change is governed by the following equation (and shown in Figure 1 in °C):

$$S_i \times T_i^{2.90} = S_f \times T_f^{2.90}$$

where S_i is the sensitivity at any initial temperature T_i , and S_f is the sensitivity at any other final temperature T_f with the temperature values in ${}^{\circ}K$.

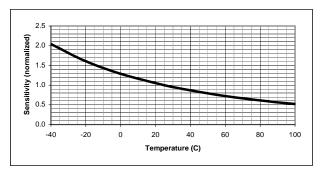


Figure 1: Thermal Accelerometer Sensitivity

In gaming applications where the game or controller is typically used in a constant temperature environment, sensitivity might not need to be compensated in hardware or software. Any compensation for this effect could be done instinctively by the game player.

For applications where sensitivity changes of a few percent are acceptable, the above equation can be approximated with a linear function. Using a linear approximation, an external circuit that provides a gain adjustment of -0.9%°C would keep the sensitivity within 10% of its room temperature value over a 0°C to +50°C range.

For applications that demand high performance, a low cost micro-controller can be used to implement the above equation. A reference design using a Microchip MCU (p/n 16F873/04-SO) and MEMSIC developed firmware is available by contacting the factory. With this reference design, the sensitivity variation over the full temperature range (-40°C to +105°C) can be kept below 3%. Please visit the MEMSIC web site at www.memsic.com for reference design information on circuits and programs including look up tables for easily incorporating sensitivity compensation.

DISCUSSION OF TILT APPLICATIONS AND MINIMUM RESOLUTION

Tilt Applications: One of the most popular applications of the MEMSIC accelerometer product line is in tilt/inclination measurement. An accelerometer uses the force of gravity as an input to determine the inclination angle of an object.

A MEMSIC accelerometer is most sensitive to changes in position, or tilt, when the accelerometer's sensitive axis is perpendicular to the force of gravity, or parallel to the Earth' surface. Similarly, when the accelerometer' axis is parallel to the force of gravity (perpendicular to the Earth' surface), it is least sensitive to changes in tilt.

Table 1 and Figure 2 help illustrate the output changes in the X- and Y-axes as the unit is tilted from +90° to 0°. Notice that when one axis has a small change in output per degree of tilt (in mg), the second axis has a large change in output per degree of tilt. The complementary nature of these two signals permits low cost accurate tilt sensing to be achieved with the MEMSIC device(reference application note AN-00MX-007).

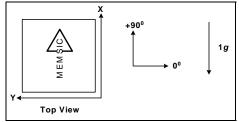


Figure 2: Accelerometer Position Relative to Gravity

	X-Axis		Y-Axis		
X-Axis					
Orientation		Change		Change	
To Earth担	X Output	per deg.	Y Output	per deg.	
Surface	(g)	of tilt	(g)	of tilt	
(deg.)	,	(mg)		(mg)	
90	1.000	0.15	0.000	17.45	
85	0.996	1.37	0.087	17.37	
80	0.985	2.88	0.174	17.16	
70	0.940	5.86	0.342	16.35	
60	0.866	8.59	0.500	15.04	
45	0.707	12.23	0.707	12.23	
30	0.500	15.04	0.866	8.59	
20	0.342	16.35	0.940	5.86	
10	0.174	17.16	0.985	2.88	
5	0.087	17.37	0.996	1.37	
0	0.000	17.45	1.000	0.15	

Table 1: Changes in Tilt for X- and Y-Axes

Resolution: The accelerometers resolution is limited by noise. The output noise floor will vary with the measurement bandwidth. With the reduction of the bandwidth, by applying an external low pass filter, the output noise drops. Reduction of bandwidth will improve the signal to noise ratio and resolution. The output noise scales directly with the square root of the measurement bandwidth. The maximum amplitude of the noise, its peak-to-peak value, approximately defines the worst case resolution of the measurement. The peak-to-peak noise is approximately equal to 6.6 times the rms value (with an average uncertainty of .1%). With a simple RC low pass filter, the rms noise is calculated as follows:

Noise (mg rms) = Noise(mg/ \sqrt{Hz})* $\sqrt{(Bandwidth(Hz)*1.6)}$

EXTERNAL FILTERS

AC Coupling: For applications where only dynamic accelerations (vibration) are to be measured, it is recommended to ac couple the accelerometer output as shown in Figure 3. The advantage of ac coupling is that zero g offset variations from part to part and zero g offset change over temperature can be eliminated. Figure 3 is a HFP (high pass filter) with a –3dB breakpoint given by the equation: $f = \frac{1}{2\pi RC}$. In many applications it may be desirable to have the HFP –3dB point at a very low frequency in order to detect very low frequency accelerations. Sometimes the implementation of this HFP may result in unreasonably large capacitors, and the designer must turn to digital implementations of HFPs where very low frequency –3dB breakpoints can be achieved.

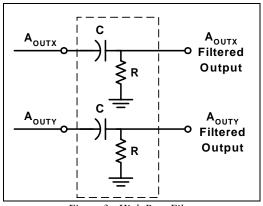


Figure 3: High Pass Filter

Low Pass Filter: An external low pass filter would be useful in low frequency applications such as tilt or inclination. The low pass filter limits the noise floor and improves the resolution of the accelerometer.

NOTE: When designing with MEMSIC ratiometric output accelerometers (MXRxxxx series), it is highly recommended that an external, 20 Hz low pass filter be used to eliminate internally generated periodic noise that is coupled to the output of the accelerometer. The low pass filter shown in Figure 4 has a –3dB breakpoint given by the equation: $f = \frac{1}{2\pi RC}$. For the 200 Hz ratiometric output device filter, C=0.1µF and R=8k Ω , ±5%, 1/8W.

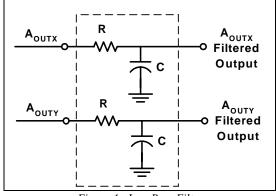


Figure 4: Low Pass Filter

COMPENSATION FOR ZERO G OFFSET CHANGE OVER TEMPERATURE

In applications where a stable zero g offset is required, and where the AC coupling external filter described earlier can not be used, analog or digital temperature compensation can be applied. The compensation requires individual calibration because the magnitude of the zero g offset change over temperature is different for each unit. To compensate the Change, a calibrated temperature dependent signal equal in magnitude but with opposite polarity is added to the accelerometer output. The circuit in Figure 5 shows a circuit example applying an analog linear compensation technique. In this circuit the accelerometer

temperature sensor output is added to or subtracted from the accelerometer output. The calibration sequence is: start at room temperature with the 100K pot set so that its wiper is at V ref. Next, soak the accelerometer at the expected extreme temperature and observe the direction of the change. Then set the switch to the non-inverting input if the change is negative or vice versa. Finally, adjust the 100K pot while monitoring the circuit output, until the zero g offset change is removed.

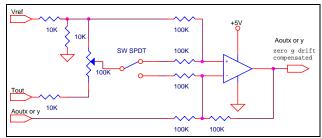


Figure 5: Zero g Offset Temperature Compensation Circuit

Various digital compensation techniques can be applied using a similar concept. Digital techniques can provide better compensation because they can compensate for nonlinear zero *g* offset vs. temperature. A micro-controller or micro-processor would perform the compensation. The acceleration signal and the temperature signal would be digitized using an analog to digital converter. Like in the analog compensation, the first step is to test and characterize the zero *g* change. The purpose of the characterization is to create a look up table or to estimate a mathematical representation of the change. For example, the change could be characterized by an equation of the form:

Change = a * Temperature ² + b * Temperature + c

where a,b,c are unique constants for each accelerometer. In normal operation the processor calculates the output:

Compensated Output = Acceleration - Change.

For a more detail discussion of temperature compensation reference MEMSIC application note #AN-00MX-02.

TEMPERATURE OUTPUT NOISE REDUCTION

It is recommended that a simple RC low pass filter is used when measuring the temperature output. Temperature output is typically a very slow changing signal, so a very low frequency filter eliminates erroneous readings that may result from the presence of higher frequency noise. A simple filter is shown in Figure 6.

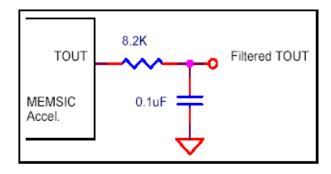


Figure 6: Temperature Output Noise Reduction

POWER SUPPLY NOISE REJECTION

Two capacitors and a resistor are recommended for best rejection of power supply noise(reference Figure 7 below). The capacitors should be located as close as possible to the device supply pins (V_{DA} , V_{DD}). The capacitor lead length should be as short as possible, and surface mount capacitors are preferred. For typical application, capacitors C1 and C2 can be ceramic $0.1\mu F$, and the resistor R can be 10Ω .

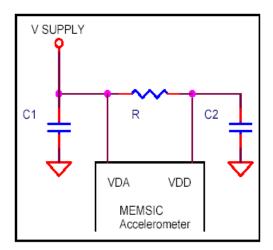


Figure 7: Power Supply Noise Rejection

PCB LAYOUT AND FABRICATION SUGGESTIONS

- 1, The Sck pin should be grounded to minimize noise.
- 2, Liberal use of ceramic bypass capacitors is recommended.
- 3, Robust low inductance ground wiring should be used.
- 4, Care should be taken to ensure there is 'Thermal symmetry' on the PCB immediately surrounding the MEMSIC device and that there is no significant heat Source nearby.
- 5, A metal ground plane should be added directly beneath the MEMSIC device. The size of the ground plane should be similar to the MEMSIC device's footprint and be as thick as possible.
- 6, Vias can be added symmetrically around the ground plane. Vias increase thermal isolation of the device from the rest of the PCB.

PACKAGE DRAWING

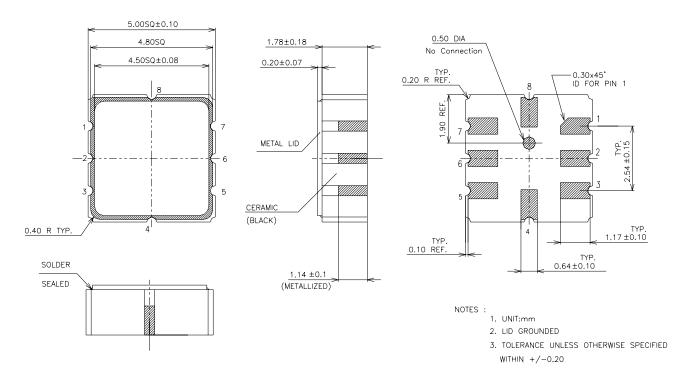


Figure 8: Hermetically Sealed Package Outline